John Budai

List of Publications by Year in Descending Order

266 papers	11,989 citations	54 h-index	101 g-index
275 ext. papers	12,579 ext. citations	5.8 avg, IF	5.59 L-index

#	Paper	IF	Citations
266	Long-Range Antiferromagnetic Order in a Rocksalt High Entropy Oxide. *Chemistry of Materials*, **2019**, 31, 3705-3711	9.6	66
265	Intrinsic anharmonic localization in thermoelectric PbSe. *Nature Communications*, **2019**, 10, 1928	17.4	34
264	Supersonic propagation of lattice energy by phasons in fresnoite. *Nature Communications*, **2018**, 9, 1823	17.4	7
263	Correspondence: Reply to 'Phantom phonon localization in relaxors'. *Nature Communications*, **2017**, 8, 1936	17.4	2
262	Boundary migration in a 3D deformed microstructure inside an opaque sample. *Scientific Reports*, **2017**, 7, 4423	4.9	16
261	Giant electromechanical coupling of relaxor ferroelectrics controlled by polar nanoregion vibrations. *Science Advances*, **2016**, 2, e1501814	14.3	61
260	Ferroelectric Self-Poling, Switching, and Monoclinic Domain Configuration in BiFeO3 Thin Films. *Advanced Functional Materials*, **2016**, 26, 5166-5173	15.6	24
259	Three-mode coupling interference patterns in the dynamic structure factor of a relaxor ferroelectric. *Physical Review B*, **2016**, 94,	3.3	4
258	X-ray microscopy: Beyond ensemble averages. *Nature Materials*, **2015**, 14, 657-8	27	
257	Nanoscale Structure in AgSbTe2 Determined by Diffuse Elastic Neutron Scattering. *Journal of Electronic Materials*, **2015**, 44, 1536-1539	1.9	2
256	Strain Doping: Reversible Single-Axis Control of a Complex Oxide Lattice via Helium Implantation. *Physical Review Letters*, **2015**, 114, 256801	7.4	64
255	Crystal structures and optical properties of new quaternary strontium europium aluminate luminescent nanoribbons. *Journal of Materials Chemistry C*, **2015**, 3, 778-788	7.1	5
254	New localized/delocalized emitting state of Eu2+ in orange-emitting hexagonal EuAl2O4. *Scientific Reports*, **2014**, 4, 7101	4.9	13
253	Phonon localization drives polar nanoregions in a relaxor ferroelectric. *Nature Communications*, **2014**, 5, 3683	17.4	80
252	Metallization of vanadium dioxide driven by large phonon entropy. *Nature*, **2014**, 515, 535-9	50.4	192
251	Inhomogeneous deformation behavior in intercrystalline regions in polycrystalline Ni. *Acta Materialia*, **2014**, 65, 393-399	8.4	8
250	Focused-ion-beam induced damage in thin films of complex oxide BiFeO3. *APL Materials*, **2014**, 2, 022109	3.7	14

249	Phonon scattering rates and atomic ordering in Ag1−xSb1+xTe2+x(x=0,0.1,0.2) investigated with inelastic neutron scattering and synchrotron diffraction. *Physical Review B*, **2014**, 90,	3.3	12
248	New Ternary Europium Aluminate Luminescent Nanoribbons for Advanced Photonics. *Advanced Functional Materials*, **2013**, 23, 1998-2006	15.6	11
247	In situ X-ray microdiffraction studies inside individual VO2 microcrystals. *Acta Materialia*, **2013**, 61, 2751-2762	4	26
246	Correlation between structure and semiconductor-to-metal transition characteristics of VO2/TiO2/sapphire thin film heterostructures. *Acta Materialia*, **2013**, 61, 7805-7815	8.4	39
245	Unit cell orientation of tetragonal-like BiFeO3 thin films grown on highly miscut LaAlO3 substrates. *Applied Physics Letters*, **2013**, 102, 221910	3.4	9
244	Role of substrate crystallographic characteristics on structure and properties of rutile TiO2 epilayers. *Journal of Applied Physics*, **2013**, 114, 044314	2.5	7
243	National School on Neutron and X-ray Scattering. *Synchrotron Radiation News*, **2013**, 26, 9-12	0.6	1
242	New yellow Ba0.93Eu0.07Al2O4 phosphor for warm-white light-emitting diodes through single-emitting-center conversion. *Light: Science and Applications*, **2013**, 2, e50-e50	16.7	334
241	Luminescent Nanoribbons: New Ternary Europium Aluminate Luminescent Nanoribbons for Advanced Photonics (Adv. Funct. Mater. 16/2013). *Advanced Functional Materials*, **2013**, 23, 1978-1978	15.6	
240	The 3D X-Ray Crystal Microscope: An Unprecedented Tool for ICME **2013**, 183-188		
239	Doping-based stabilization of the M2 phase in free-standing VO2 nanostructures at room temperature. *Nano Letters*, **2012**, 12, 6198-205	11.5	120
238	Phase-specific elastic/plastic interface interactions in layered NiAl–Cr(Mo) structures. *Acta Materialia*, **2012**, 60, 3279-3286	8.4	19
237	Compositional disorder, polar nanoregions and dipole dynamics in Pb(Mg1/3Nb2/3)O3-based relaxor ferroelectrics. *Zeitschrift Für Kristallographie*, **2011**, 226, 99-107		42
236	The race to x-ray microbeam and nanobeam science. *Science*, **2011**, 334, 1234-9	33.3	231
235	Spectroscopic dielectric tensor of monoclinic crystals: CdWO4. *Physical Review B*, **2011**, 84,	3.3	39
234	Electromechanical actuation and current-induced metastable states in suspended single-crystalline VO2 nanoplatelets. *Nano Letters*, **2011**, 11, 3065-73	11.5	47
233	Lattice-Symmetry-Driven Phase Competition in Vanadium Dioxide. *Materials Research Society Symposia Proceedings*, **2011**, 1292, 67		1
232	Direct evidence of mesoscopic dynamic heterogeneities at the surfaces of ergodic ferroelectric relaxors. *Physical Review B*, **2010**, 81,	3.3	71

231	Interplay between ferroelastic and metal-insulator phase transitions in strained quasi-two-dimensional VO2 nanoplatelets. *Nano Letters*, **2010**, 10, 2003-11	11.5	91
230	Symmetry relationship and strain-induced transitions between insulating M1 and M2 and metallic R phases of vanadium dioxide. *Nano Letters*, **2010**, 10, 4409-16	11.5	125
229	High-resolution x-ray and light beam induced current (LBIC) measurements of multcrystalline silicon solar cells **2010**,		1
228	Nonpolar ZnO film growth and mechanism for anisotropic in-plane strain relaxation. *Acta Materialia* , **2010**, 58, 1097-1103	8.4	58
227	Structural characterization of two-step growth of epitaxial ZnO films on sapphire substrates at low temperatures. *Journal Physics D: Applied Physics*, **2009**, 42, 105409	3	21
226	Epitaxial growth of transparent tin oxide films on (0001) sapphire by pulsed laser deposition. *Materials Research Bulletin*, **2009**, 44, 6-10	5.1	32
225	Zinc Oxide Microtowers by Vapor Phase Homoepitaxial Regrowth. *Advanced Materials*, **2009**, 21, 890-896	24	32
224	Elastically driven anisotropic percolation in electronic phase-separated manganites. *Nature Physics*, **2009**, 5, 885-888	16.2	143
223	At the limit of polychromatic microdiffraction. *Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing*, **2009**, 524, 3-9	5.3	22
222	Thin film epitaxy and structure property correlations for non-polar ZnO films. *Acta Materialia*, **2009**, 57, 4426-4431	8.4	34
221	Structure and magnetism of cobalt-doped ZnO thin films. *New Journal of Physics*, **2008**, 10, 065002	2.9	150
220	Synthesis and characterization of porous TiO2 with wormhole-like framework structure. *Journal of Porous Materials*, **2008**, 15, 21-27	2.4	8
219	Formation of oxidation-resistant Cu-Mg coatings on (001) Cu for oxide superconducting tapes. *Surface and Coatings Technology*, **2008**, 202, 5136-5139	4.4	3
218	Polychromatic X-ray micro- and nanodiffraction for spatially-resolved structural studies. *Thin Solid Films*, **2008**, 516, 8013-8021	2.2	23
217	Ferromagnetism in pseudocubic BaFeO3 epitaxial films. *Applied Physics Letters*, **2008**, 92, 012514	3.4	32
216	S186 Invited X-ray Microdiffraction Techniques for Measuring Local Microstructure and Strain Distributions. *Powder Diffraction*, **2008**, 23, 189-189	1.8	
215	Characterization of growth defects in thin GaN layers with X-ray microbeam. *Physica Status Solidi (B): Basic Research*, **2007**, 244, 1735-1742	1.3	6
214	Orientation and growth behavior of CaHfO3 thin films on non-oxide substrates. *Materials Letters*, **2007**, 61, 3500-3503	3.3	2

213	Nanostructured GaN nucleation layer for light-emitting diodes. *Journal of Nanoscience and Nanotechnology*, **2007**, 7, 2719-25	1.3	4
212	Spatially Resolved Characterization of Microstructure, Defects and Tilts in GaN Layers Grown on Si(111) Substrates by Maskless Cantilever Epitaxy. *Materials Research Society Symposia Proceedings*, **2006**, 934, 1		
211	Spatially resolved distribution of dislocations and crystallographic tilts in GaN layers grown on Si(111) substrates by maskless cantilever epitaxy. *Journal of Applied Physics*, **2006**, 100, 053103	2.5	17
210	Growth of ZnO thin films on c-plane Al2O3 by molecular beam epitaxy using ozone as an oxygen source. *Applied Surface Science*, **2006**, 252, 7442-7448	6.7	38
209	High-performance Kirkpatrick-Baez supermirrors for neutron milli- and micro-beams. *Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing*, **2006**, 437, 120-125	5.3	19
208	Phase stability and orientation of SrCu2O2 films grown by pulsed laser deposition. *Thin Solid Films*, **2005**, 488, 173-177	2.2	8
207	KirkpatrickBaez microfocusing optics for thermal neutrons. *Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment*, **2005**, 539, 312-320	1.2	34
206	Properties of anatase CoxTi1O2 thin films epitaxially grown by reactive sputtering. *Thin Solid Films*, **2005**, 488, 194-199	2.2	13
205	Polychromatic X-ray microdiffraction studies of mesoscale structure and dynamics. *Journal of Synchrotron Radiation*, **2005**, 12, 155-62	2.4	66
204	Annealing-environment effects on the properties of CoPt nanoparticles formed in single-crystal Al2O3 by ion implantation. *Journal of Applied Physics*, **2005**, 98, 114311	2.5	9
203	Investigation of TiN seed Layers for RABiTS architectures with a single-Crystal-like out-of-plane texture. *IEEE Transactions on Applied Superconductivity*, **2005**, 15, 2981-2984	1.8	15
202	Spatial distribution and electronic state of Co in epitaxial anatase CoxTi1O2 thin films grown by reactive sputtering. *Applied Physics Letters*, **2004**, 84, 2608-2610	3.4	59
201	FePt nanoparticles formed in Al2O3 by ion beam synthesis: Annealing environment effects. *Journal of Applied Physics*, **2004**, 95, 8160-8166	2.5	17
200	2D and 3D X-Ray Structural Microscopy Using Submicron-Resolution Laue Microdiffraction. *Materials Research Society Symposia Proceedings*, **2004**, 840, Q7.1.1		1
199	Deformation microstructure under microindents in single-crystal Cu using three-dimensional x-ray structural microscopy. *Journal of Materials Research*, **2004**, 19, 66-72	2.5	38
198	Epitaxial growth of anatase by reactive sputter deposition using water vapor as the oxidant. *Thin Solid Films*, **2004**, 446, 18-22	2.2	26
197	Differential-aperture X-ray structural microscopy: a submicron-resolution three-dimensional probe of local microstructure and strain. *Micron*, **2004**, 35, 431-9	2.3	48
196	The three-dimensional X-ray crystal microscope: A new tool for materials characterization. *Metallurgical and Materials Transactions A: Physical Metallurgy and Materials Science*, **2004**, 35, 1963-1967	2.3	46

195	Micron-resolution 3-D measurement of local orientations near a grain-boundary in plane-strained aluminum using X-ray microbeams. *International Journal of Plasticity*, **2004**, 20, 543-560	7.6	31
194	Reactive sputter deposition of epitaxial (001) CeO2 on (001) Ge. *Thin Solid Films*, **2004**, 468, 1-3	2.2	8
193	Cathodoluminescence from Thin Film Zn[sub 2]GeO[sub 4]:Mn Phosphor Grown by Pulsed Laser Deposition. *Journal of the Electrochemical Society*, **2004**, 151, H188	3.9	43
192	Fabrication of high J/sub c/YBa/sub 2/Cu/sub 3/O/sub 7-/spl delta// tapes using the newly developed lanthanum manganate single buffer layers. *IEEE Transactions on Applied Superconductivity*, **2003**, 13, 2481-2483	1.8	25
191	Epitaxial (La,Sr)TiO3 as a conductive buffer for high temperature superconducting coated conductors. *Solid-State Electronics*, **2003**, 47, 2177-2181	1.7	17
190	Properties of Mn-doped Cu2O semiconducting thin films grown by pulsed-laser deposition. *Solid-State Electronics*, **2003**, 47, 2215-2220	1.7	63
189	Magnetic properties of Co- and Mn-implanted BaTiO3, SrTiO3 and KTaO3. *Solid-State Electronics*, **2003**, 47, 2225-2230	1.7	60
188	Ferromagnetism in Co- and Mn-doped ZnO. *Solid-State Electronics*, **2003**, 47, 2231-2235	1.7	86
187	Conductivity in transparent anatase TiO2 films epitaxially grown by reactive sputtering deposition. *Solid-State Electronics*, **2003**, 47, 2275-2278	1.7	71
186	Advances in wide bandgap materials for semiconductor spintronics. *Materials Science and Engineering Reports*, **2003**, 40, 137-168	30.9	375
185	Epitaxial structure and transport in LaTiO3+x films on (001) SrTiO3. *Physica Status Solidi A*, **2003**, 200, 346-351		21
184	Evidence for pseudo-gap behavior in defect-doped infinite layer (Ca, Sr)CuO2 thin films. *Physica Status Solidi (B): Basic Research*, **2003**, 236, 143-150	1.3	
183	Ferromagnetism in cobalt-implanted ZnO. *Applied Physics Letters*, **2003**, 83, 5488-5490	3.4	241
182	Through-thickness superconducting and normal-state transport properties revealed by thinning of thick film ex situ YBa2Cu3O7 coated conductors. *Applied Physics Letters*, **2003**, 83, 3951-3953	3.4	35
181	Spectroscopic ellipsometry of thin film and bulk anatase (TiO2). *Journal of Applied Physics*, **2003**, 93, 9537-9541	2.5	223
180	X-ray microdiffraction study of growth modes and crystallographic tilts in oxide films on metal substrates. *Nature Materials*, **2003**, 2, 487-92	27	108
179	Ion beam synthesis of magnetic CoPt alloys in Al2O3. *Journal of Magnetism and Magnetic Materials*, **2003**, 260, 319-329	2.8	28
178	Effects of Co Implantation in BaTiO[sub 3], SrTiO[sub 3], and KTaO[sub 3]. *Electrochemical and Solid-State Letters*, **2003**, 6, J1		5

177	Properties of Mn-Implanted BaTiO[sub 3], SrTiO[sub 3], and KTaO[sub 3]. *Electrochemical and Solid-State Letters*, **2003**, 6, G19		30
176	Spatially resolved Poisson strain and anticlastic curvature measurements in Si under large deflection bending. *Applied Physics Letters*, **2003**, 82, 3856-3858	3.4	41
175	Oriented ferromagnetic Fe-Pt alloy nanoparticles produced in Al2O3 by ion-beam synthesis. *Journal of Applied Physics*, **2003**, 93, 5656-5669	2.5	45
174	X-ray Microbeam Investigation of Deformation Microstructure in Microindented Cu. *Materials Research Society Symposia Proceedings*, **2003**, 779, 5341		7
173	Ferromagnetic FePt nanoparticles formed in Al2O3 by ion implantation. *Nuclear Instruments & Methods in Physics Research B*, **2002**, 191, 437-441	1.2	18
172	Epitaxial growth of CeO2 on (100) InP using reactive r.f. magnetron sputtering. *Applied Physics A: Materials Science and Processing*, **2002**, 75, 699-702	2.6	4
171	(La,Sr)TiO3 as a conductive buffer for RABiTS coated conductors. *Physica C: Superconductivity and Its Applications*, **2002**, 372-376, 818-820	1.3	4
170	Epitaxial stabilization of single crystal anatase films via reactive sputter deposition. *Thin Solid Films*, **2002**, 422, 166-169	2.2	36
169	Three-dimensional X-ray structural microscopy with submicrometre resolution. *Nature*, **2002**, 415, 887-90	30.4	597
168	Magnetic force microscopy of ferromagnetic nanoparticles formed in Al2O3 and SiO2 by ion implantation. *Journal of Applied Physics*, **2002**, 92, 6200-6204	2.5	20
167	Hydrogen-assisted pulsed-laser deposition of epitaxial CeO2 films on (001)InP. *Applied Physics Letters*, **2002**, 80, 106-108	3.4	6
166	Photo- and low-voltage cathodoluminescence in lithium zinc gallate blue and green thin-film phosphors. *Journal of Applied Physics*, **2002**, 91, 2974-2977	2.5	15
165	Buried superconducting layers comprised of magnesium diboride nanocrystals formed by ion implantation. *Applied Physics Letters*, **2002**, 80, 4786-4788	3.4	16
164	Strontium silicide termination and silicate epitaxy on (001) Si. *Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena*, **2002**, 20, 257		20
163	Etching-enhanced Ablation and the Formation of a Microstructure in Silicon by Laser Irradiation in an SF6 Atmosphere. *Journal of Materials Research*, **2002**, 17, 1002-1013	2.5	22
162	Deformation Microstructure Under Nanoindentations in Cu Using 3D X-Ray Structural Microscopy. *Materials Research Society Symposia Proceedings*, **2002**, 750, 1		4
161	Deformation Microstructure Under Nanoindentations in Cu Using 3D X-Ray Structural Microscopy. *Materials Research Society Symposia Proceedings*, **2002**, 750, 1		1
160	Photoluminescence Dynamics of CdS Nanocrystals Fabricated by Sequential Ion Implantation. *Japanese Journal of Applied Physics*, **2001**, 40, 2092-2094	1.4	10

159	Critical current density of YBa2Cu3O7□low-angle grain boundaries in self-field. *Applied Physics Letters*, **2001**, 78, 2031-2033	3.4	34
158	Enhanced ultraviolet photoconductivity in semiconducting ZnGa2O4 thin films. *Journal of Applied Physics*, **2001**, 90, 3863-3866	2.5	31
157	. *IEEE Transactions on Magnetics*, **2001**, 37, 2197-2199	2	15
156	Formation of Ferromagnetic FePt Nanoparticles by Ion Implantation. *Materials Research Society Symposia Proceedings*, **2001**, 704, 771		1
155	Epitaxial Oxide Thin-Film Phosphors for Low Voltage FED Applications. *Materials Research Society Symposia Proceedings*, **2000**, 621, 241		1
154	Epitaxial yttria-stabilized zirconia on biaxially-textured (001) Ni for YBCO coated conductor. *Physica C: Superconductivity and Its Applications*, **2000**, 341-348, 2481-2482	1.3	12
153	Epitaxial Growth and Luminescent Properties of Mn2+-Activated ZnGa2O4 Films **2000**, 4, 293-297		6
152	The Effect of Size, Strain, and Long-Range Interactions on Ferroelectric Phase Transitions in KNbO3KTaO3KNbO3 Superlattices Studied by X-ray, EXAFS, and Dielectric Measurements **2000**, 4, 279-287		11
151	Optical characterization of CdS nanocrystals in Al2O3 matrices fabricated by ion-beam synthesis. *Applied Physics Letters*, **2000**, 77, 2289-2291	3.4	52
150	Pulsed-laser deposition of electronic oxides: superconductor and semiconductor applications **2000**, 3933, 124		
149	Magneto-optical effects from nanophase □Fe and Fe3O4 precipitates formed in yttrium-stabilized ZrO2 by ion implantation and annealing. *Applied Physics Letters*, **2000**, 77, 711-713	3.4	29
148	Photo- and cathodoluminescence characteristics of blue-light-emitting epitaxial Sr2CeO4 thin-film phosphors. *Applied Physics Letters*, **2000**, 77, 678-680	3.4	37
147	Nucleation of epitaxial yttria-stabilized zirconia on biaxially textured (001) Ni for deposited conductors. *Applied Physics Letters*, **2000**, 76, 2427-2429	3.4	33
146	Hydrogen-assisted pulsed-laser deposition of (001)CeO2 on (001) Ge. *Applied Physics Letters*, **2000**, 76, 1677-1679	3.4	40
145	Optical and structural properties of ZnO films deposited on GaAs by pulsed laser deposition. *Journal of Applied Physics*, **2000**, 88, 201-204	2.5	210
144	A transmission electron microscopy investigation of sulfide nanocrystals formed by ion implantation. *Journal of Materials Research*, **1999**, 14, 4489-4502	2.5	36
143	Formation and phase transition of VO2 precipitates embedded in sapphire. *Journal of Materials Research*, **1999**, 14, 2602-2610	2.5	16
142	Formation of oriented particles in an amorphous host: ZnS nanocrystals in silicon. *Applied Physics Letters*, **1999**, 74, 697-699	3.4	13

141	Effects of hydrogen in the annealing environment on photoluminescence from Si nanoparticles in SiO2. *Journal of Applied Physics*, **1999**, 86, 396-401	2.5	111
140	Alternating transport-current flow in superconductive films: The role of a geometrical barrier to vortex motion. *Physical Review B*, **1999**, 60, 6878-6883	3.3	14
139	Long length fabrication of YBCO on rolling assisted biaxially textured substrates (RABiTS) using pulsed laser deposition. *IEEE Transactions on Applied Superconductivity*, **1999**, 9, 2276-2279	1.8	27
138	Plume-induced stress in pulsed-laser deposited CeO2 films. *Applied Physics Letters*, **1999**, 74, 2134-2136	3.4	28
137	Enhanced photoluminescence in epitaxial ZnGa2O4:Mn thin-film phosphors using pulsed-laser deposition. *Applied Physics Letters*, **1999**, 74, 3155-3157	3.4	78
136	X-Ray Microbeam Measurement of Local Texture and Strain in Metals. *Materials Research Society Symposia Proceedings*, **1999**, 563, 169		14
135	Strain and Texture in Al-Interconnect Wires Weasured by X-Xay Microbeam Diffraction. *Materials Research Society Symposia Proceedings*, **1999**, 563, 175		24
134	The Formation of High-Coercivity, Oriented, Nanophase Cobalt Precipitates in Al2O3 Single Crystals by Ion Implantation. *Materials Research Society Symposia Proceedings*, **1999**, 581, 71		7
133	Epitaxial Electronic Oxides on Semiconductors Using Pulsed-Laser Deposition. *Materials Research Society Symposia Proceedings*, **1999**, 587, O3.7.1		
132	3-D Measurement of Deformation Microstructure in Al(0.2%)Mg Using Submicron Resolution White X-ray Microbeams. *Materials Research Society Symposia Proceedings*, **1999**, 590, 247		14
131	Epitaxial Film Growth of Tl0.78Bi0.22Sr1.6Ba0.4Ca2Cu3O9 on Rolling Assisted Biaxially Textured Nickel Substrates with YSZ And CeO2 Buffer Layers. *Journal of Superconductivity and Novel Magnetism*, **1998**, 11, 159-161		17
130	High Critical Current Density YBa2Cu3O x Tapes Using the RABiTs Approach. *Journal of Superconductivity and Novel Magnetism*, **1998**, 11, 481-487		39
129	Selenium nanoparticles formed by ion implantation into fused silica. *Nuclear Instruments & Methods in Physics Research B*, **1998**, 141, 284-288	1.2	7
128	The role of defect excesses in damage formation in Si during ion implantation at elevated temperature. *Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing*, **1998**, 253, 240-248	5.3	18
127	Epitaxial YBa2Cu3O7 films on rolled-textured metals for high-temperature superconducting applications. *Materials Science and Engineering B: Solid-State Materials for Advanced Technology*, **1998**, 56, 86-94	3.1	40
126	Bend strain tolerance of critical currents for YBa2Cu3O7 films deposited on rolled-textured (001)Ni. *Applied Physics Letters*, **1998**, 73, 1904-1906	3.4	49
125	Characterization of zinc implanted silica: Effects of thermal annealing and picosecond laser radiation. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **1998**, 16, 1409-1413	2.9	35
124	Optical Properties of Si Nanocrystals Formed in SiO2 by Ion Implantation. *Materials Research Society Symposia Proceedings*, **1998**, 507, 249		11

123	Formation of ZnAl2O4 and MgAl2O4 Spinel in Al2O3 by Ion Implantation. *Materials Research Society Symposia Proceedings*, **1998**, 540, 219		5
122	Ion-Implantation/Annealing-Induced Precipitation of Nanophase Ferromagnetic Particles in Yttrium-Stabilized ZrO2. *Materials Research Society Symposia Proceedings*, **1998**, 540, 225		12
121	Nanostructured Arrays Formed by Finely Focused Ion Beams. *Materials Research Society Symposia Proceedings*, **1998**, 536, 251		2
120	Semiconducting epitaxial films of metastable SrRu0.5Sn0.5O3 grown by pulsed laser deposition. *Applied Physics Letters*, **1997**, 70, 2147-2149	3.4	27
119	Influence of oxygen background pressure on crystalline quality of SrTiO3 films grown on MgO by pulsed laser deposition. *Applied Physics Letters*, **1997**, 71, 1709-1711	3.4	22
118	Conductors with controlled grain boundaries: An approach to the next generation, high temperature superconducting wire. *Journal of Materials Research*, **1997**, 12, 2924-2940	2.5	150
117	A New Approach to the Fabrication of Smart Near-Surface Nanostructure Composites. *Materials Research Society Symposia Proceedings*, **1997**, 501, 137		3
116	Ion Beam Synthesis Of Cds, ZnS, And PbS Compound Semiconductor Nanocrystals. *Materials Research Society Symposia Proceedings*, **1997**, 504, 399		6
115	Epitaxial Growth of Oxide Thin Films on (001) Metal Surfaces Using Pulsed-Laser Deposition. *Materials Research Society Symposia Proceedings*, **1997**, 474, 401		2
114	Temperature Dependence and Annealing Effects of Absorption Edges for Selenium Quantum Dots Formed By Ion Implantation in Silica Glass. *Materials Research Society Symposia Proceedings*, **1997**, 481, 501		
113	Alternating current losses in biaxially textured YBa2Cu3O7 films deposited on Ni tapes. *Applied Physics Letters*, **1997**, 71, 2029-2031	3.4	30
112	Low cost, single crystal-like substrates for practical, high efficiency solar cells **1997**,		5
111	Synthesis and Physical Properties of Semiconductor Nanocrystals Formed by Ion Implantation. *ACS Symposium Series*, **1997**, 198-212	0.4	2
110	High quality optoelectronic grade epitaxial AlN films on Al2O3, Si and 6H-SiC by pulsed laser deposition. *Thin Solid Films*, **1997**, 299, 94-103	2.2	46
109	Deposition of biaxially-oriented metal and oxide buffer-layer films on textured Ni tapes: new substrates for high-current, high-temperature superconductors. *Physica C: Superconductivity and Its Applications*, **1997**, 275, 155-161	1.3	110
108	Epitaxial superconducting thin films Tl0.78Bi0.22Sr1.6Ba0.4Ca2O9 on (001) YSZ synthesized by laser ablation and post-annealing in pure argon. *Physica C: Superconductivity and Its Applications*, **1997**, 277, 13-18	1.3	14
107	Controlling the size, structure and orientation of semiconductor nanocrystals using metastable phase recrystallization. *Nature*, **1997**, 390, 384-386	50.4	95
106	Growth of biaxially textured buffer layers on rolled-Ni substrates by electron beam evaporation. *Physica C: Superconductivity and Its Applications*, **1997**, 275, 266-272	1.3	169

105	Development of Biaxially Textured Buffer Layers on Rolled-Ni Substrates for High Current YBa2Cu3O7-y Coated Conductors **1997**, 669-672		1
104	Fabrication of High Critical Current Density Superconducting Tapes by Epitaxial Deposition of YBCO Thick Films on Biaxially Textured Metal Substrates **1997**, 685-688		
103	High critical current density superconducting tapes by epitaxial deposition of YBa2Cu3Ox thick films on biaxially textured metals. *Applied Physics Letters*, **1996**, 69, 1795-1797	3.4	885
102	Addendum: Ion beam synthesis and stability of GaAs nanocrystals in silicon [Appl. Phys. Lett. 68, 2389 (1996)]. *Applied Physics Letters*, **1996**, 69, 2297-2297	3.4	2
101	Ion-beam synthesis and stability of GaAs nanocrystals in silicon. *Applied Physics Letters*, **1996**, 68, 2389-2391	3.4	29
100	GaAs nanocrystals formed by sequential ion implantation. *Journal of Applied Physics*, **1996**, 79, 1876-1880	2.5	57
99	Artificially-layered and metastable thin-film materials development utilizing pulsed-laser deposition. *Materials Science and Engineering B: Solid-State Materials for Advanced Technology*, **1996**, 41, 374-378	3.1	1
98	The growth and properties of epitaxial KNbO3 thin films and KNbO3/KTaO3 superlattices. *Applied Physics Letters*, **1996**, 68, 1488-1490	3.4	84
97	Epitaxial YBa2Cu3O7 on Biaxially Textured Nickel (001): An Approach to Superconducting Tapes with High Critical Current Density. *Science*, **1996**, 274, 755-757	33.3	639
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